

## Applications

- Video signal distribution in HFC and FTTx nodes
- CWDM
- Signal distribution in L-band and wireless remoting links
- High linearity, low power fiber links


## Features

- Linear DFB laser design
- Bandwidth > 4000 MHz
- RoHS compliance
- Optical Isolator
- Monitor photodiode
- Asperic lens
- High slope efficiency


## Model 3955 DFB 1550nm Laser in TO-can

Emcore's Model 3955 DFB laser in TO-can offers a low cost solution for linear fiberoptic links. These components can be cooled with external thermo-electric coolers for high stability, or run without TEC's to reduce power consumption. The DFB laser in TO-can builds upon Ortel's long history of high performance, leading edge designs in CATV, CWDM, wireless, and high speed digital applications. The laser diode chip is mounted on a compact hermetic TO-can assembly together with monitor photodiode and isolator, for flexible integration into the pigtail package configuration.

Performance Highlights

|  | Min | Typical | Max | Units |
| :--- | :---: | :---: | :---: | :---: |
| Operating Case Temperature Range | -40 | - | 85 | ${ }^{\circ} \mathrm{C}$ |
| Frequency Range | 5 | - | 4000 | MHz |
| Slope Efficiency | 0.35 | - | - | $\mathrm{mW} / \mathrm{mA}$ |
| Center Wavelength Range | 1467 | - | 1610 | nm |
| Side Mode Suppression Ratio, CW | 30 | - | - | dB |

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## Absolute Maximum Ratings ${ }^{1}$

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

| Parameters | Symbol | Condition/Notes | MIN | MAX | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Storage Temperature | $\mathrm{T}_{\text {STG }}$ | Non-Operating | -40 | 85 | ${ }^{\circ} \mathrm{C}$ |
| Operating Case Temperature | $\mathrm{T}_{\mathrm{OP}}$ | Continuous | -40 | 85 | ${ }^{\circ} \mathrm{C}$ |
| Laser Diode Forward Current | $\mathrm{I}_{\mathrm{OP}}$ | CW | - | 150 | mA |
| Laser Diode Reverse Voltage | $\mathrm{V}_{\mathrm{R}}$ | Continuous | - | 1.0 | V |
| Photodiode Forward Current | $\mathrm{I}_{\mathrm{MPD}}$ | Continuous | - | 2 | mA |
| Photodiode Reverse Voltage | $\mathrm{V}_{\mathrm{MPD}, \mathrm{R}}$ | Continuous | - | 10 | V |
| Average RF Input Power | PIN | 60 Seconds | - | 62 | dBmV |
| Lead Soldering Temperature/Time | - | - | - | $260 / 10$ | ${ }^{\circ} \mathrm{C} / \mathrm{sec}$ |
| Relative Humidity | RH | Continuous | - | 85 | $\%$ |
| ESD | - | Human Body Model | -500 | +500 | V |

1. Absolute maximum data are limited to system design only; proper device performance is not guaranteed over rating listed above. Operation beyond these maximum conditions may degrade device performance, lead to device failure, shorter lifetime, and will invalidate the device warranty.

## Electrical/Optical Characteristics

| Parameters | Symbol | Conditions/Notes | Min | Typ | Max | Unit | Note |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Series Resistance | $\mathrm{R}_{\mathrm{S}}$ | Between $\mathrm{I}_{\mathrm{F}}=20$ and 80 mA | 2 | - | 8 | Ohm |  |
| Forward Voltage | $\mathrm{V}_{\mathrm{F}}$ | At laser threshold | - | - | 1.8 | V |  |
| Threshold Current | $\mathrm{I}_{\mathrm{Th}}$ | - | - | 8 | 15 | mA |  |
| Slope Efficiency | SE |  | - | 0.35 | - | - | $\mathrm{W} / \mathrm{A}$ |
| Monitor Current | $\mathrm{I}_{\text {Mon }}$ | $\mathrm{I}_{\mathrm{f}}=40 \mathrm{~mA}, \mathrm{~V}_{\mathrm{MPD}}=5 \mathrm{Vdc}$ | 200 | - | 2000 | $\mu \mathrm{~A}$ |  |
| Monitor Dark Current | $\mathrm{I}_{\text {Mon,dark }}$ | $\mathrm{V}_{\text {MPD }}=5 \mathrm{Vdc}$ | - | - | 50 | nA |  |
| Linearity | $\mathrm{L} \mathrm{\eta}$ | Between 30 and 80 mA |  |  | 1 |  | 2 |
| Center Emission Wavelength | $\lambda_{\mathrm{C}}$ | Iop, Top $=25^{\circ} \mathrm{C}$ | Center WL $\pm 2 \mathrm{~nm}$ |  |  |  |  |
| Spectral Width | $\Delta \lambda$ | - | - | - | 1.0 | nm | 3,4 |
| Side Mode Suppression Ratio | SMSR | - | 30 | 40 | - | dB | 3,4 |

## Notes:

1. Slope efficiency is measured in a current range between $I_{\mathrm{th}}+5 \mathrm{~mA}$ and $\mathrm{I}_{\mathrm{th}}+65 \mathrm{~mA}$.
2. Linearity is calculated by first determining slopes of five sequential pairs of points along the linear portion of the Poc vs. IF curve $\left(\eta_{1}, \eta_{2}, \ldots, \eta_{5}\right)$ in the drive current range ( 30 mA and 80 mA ). The difference between the maximum and minimum of these slopes divided by the slope efficiency (defined as the slope of linear regression) defines Linearity.

$$
L_{\eta}=\frac{\operatorname{Max}\left\{\eta_{1}, \eta_{2}, \ldots \ldots, \eta_{5}\right\}-\operatorname{Min}\left\{\eta_{1}, \eta_{2}, \ldots \ldots, \eta_{5}\right\}}{\eta}
$$

3. Spectrum is measured using an optical spectrum analyzer with a spectral resolution better than 0.1 nm .
4. Lot sample test at $20 \%$.

## Package Outline Drawing

8.6mm Focal Length Option

10.1mm Focal Length Option


## Notes:

1. All the isolated pins $(2,3$, and 4$)$ shall be completed isolated from the case, no shortage between the ground pin (pin 1) and all other three pins.
2. Dimensional tolerances
a. Chip location in relative to the TO header center shall be within +/-30um in both $X \& Y$ direction, and $+/-30$ um in z-direction (axial).
b. Cap concentricity in relative to the TO header shall be within 50 um in radius.
c. Lead length: $14 \mathrm{~mm}+/-0.5 \mathrm{~mm}$

## Package Outline Drawing

All parts will have ink marking on the side of the base of the TO-56 with the following description.

| INK MARKING | PART DESCRIPTION |
| :---: | :---: |
| A38 | TO-CAN, CWDM DFB, ROHS, 8.6MM, PINOUT A |
| A41 | TO-CAN, CWDM DFB, ROHS, 8.6MM, PINOUT C |
| A46 | TO-CAN, CWDM DFB, ROHS, 10.1MM, PINOUT A |
| A47 | TO-CAN, CWDM DFB, ROHS, 10.1MM, PINOUT C |

## Pinout Configurations

Schematic and Pinout A


Pin Definitions for Pinout A

| Pin | Description |
| :---: | :---: |
| 1 | LD Anode, Case Ground |
| 2 | LD Cathode |
| 3 | PD Cathode |
| 4 | PD Anode |

Bottom View

Pin Definitions for Pinout C

| Pin | Description |
| :---: | :---: |
| 1 | Case |
| 2 | LD Cathode |
| 3 | PD Anode |
| 4 | LD Anode, PD Cathode |

(1)

CASE

Bottom View

## Laser Safety

This product meets the appropriate standard in Title 21 of the Code of Federal Regulations (CFR). FDA/CDRH Class 1 laser product. This device has been classified with the FDA/CDRH under accession number 0220309.

All Versions of this laser are Class 1 laser product, tested according to IEC 60825-1:2007/EN 60825-1:2007
Wavelength $=1.5 \mu \mathrm{~m}$.
Maximum power $=30 \mathrm{~mW}$.
Because of size constraints, laser safety labeling (including an FDA class 1 label) is not affixed to the module, but attached to the outside of the shipping carton.

Product is not shipped with power supply.
Caution: Use of controls, adjustments and procedures other than those specified herein may result in hazardous laser radiation exposure.


## Ordering Code Definitions



## Example

3955-1550-A-08: 1550nm Laser in TO-can, Pinout A, 8.6 mm Focal Length.
3955-1550-A-10: 1550nm Laser in TO-can, Pinout A. 10.1 mm Focal Length.

Fax: 626-293-3428


[^0]:    See following pages for complete specifications and conditions.

